



IGBT Modules

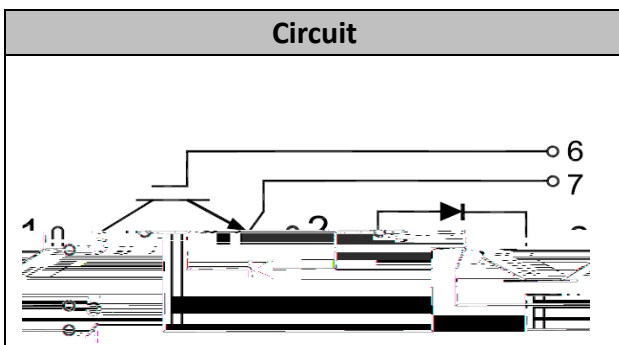
V_{CES} 1200V
I_C 150A

Applications

- Inverter for motor drive
- AC and DC servo drive amplifier
- UPS (Uninterruptible Power Supplies)
- Soft switching welding machine

Features

- Low V_{ce(sat)} with Trench technology
- V_{ce(sat)} with positive temperature coefficient
- High short circuit capability(10us)
- Including ultra fast & soft recovery anti-parallel FWD
- Low inductance
- Maximum junction temperature 175°C



● IGBT

Absolute Maximum Ratings

Parameter	Symbol	Conditions	Value	Unit
Collector-Emitter Voltage	V _{CES}	V _{GE} =0V, I _C =1mA, T _{vj} =25°C	1200	V
Continuous Collector Current	I _C	T _c =100°C	150	A
Repetitive Peak Collector Current	I _{CRM}	t _p =1ms	300	A
Gate-Emitter Voltage	V _{GES}	T _{vj} =25°C	±20	V
Total Power Dissipation	P _{tot}	T _c =25°C T _{vjmax} =175°C	968	W



MG150HF12TLC1



Characteristic values

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Gate-emitter Threshold Voltage	$V_{GE(th)}$	$V_{GE}=V_{CE}, I_C=5mA, T_{vj}=25^{\circ}C$	5.0	5.7	6.5	V
Collector-Emitter Cut-off Current	I_{CES}	$V_{CE}=1200V, V_{GE}=0V, T_{vj}=25$			1.0	mA
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=150A, V_{GE}=15V, T_{vj}=25^{\circ}C$		1.90	2.20	V
		$I_C=150A, V_{GE}=15V, T_{vj}=125^{\circ}C$		2.20		
Input Capacitance	C_{ies}	$V_{CE}=25V, V_{GE}=0V,$ $f=1MHz, T_{vj}=25$		9.8		nF
Reverse Transfer Capacitance	C_{res}			0.48		nF
Internal Gate Resistance	R_{gint}			2.5		Ω
Gate-Emitter leakage current	I_{GES}	$V_{CE}=0V, V_{GE}=20V, T_{vj}=25^{\circ}C$			400	nA
Turn-on Delay Time	$t_{d(on)}$			185		ns
Rise Time	t_r			55		ns
Turn-off Delay Time	$t_{d(off)}$		$I_C=150A$ $V_{CE}=600V$		360	
Fall Time	t_f	$V_{GES} \pm 15V$ $R_G=5.1$ $T_{vj}=25^{\circ}C$		115		ns
Energy Dissipation During Turn-on Time	E_{on}					



● Diode

Absolute Maximum Ratings

Parameter	Symbol	Conditions	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	$T_{vj}=25^{\circ}C$	1200	V
Continuous DC Forward Current	I_F		150	A



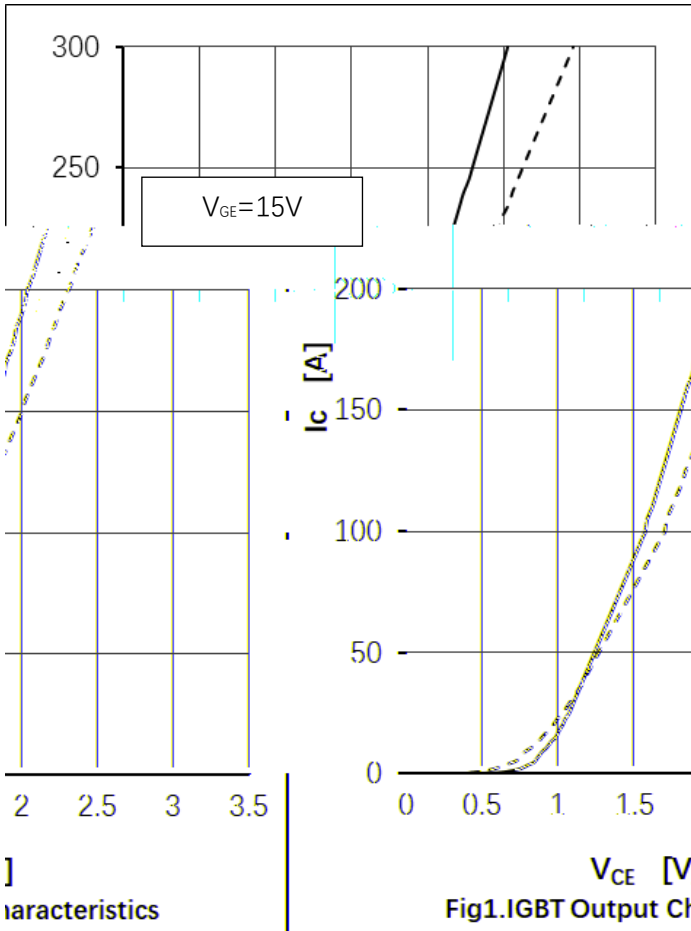
● Module Characteristics

$T_c=25^{\circ}\text{C}$ unless otherwise specified

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Isolation voltage	V_{isol}	$t=1\text{min}, f=50\text{Hz}$	2500			V
Maximum Junction Temperature □	T_{jmax}				175	$^{\circ}\text{C}$

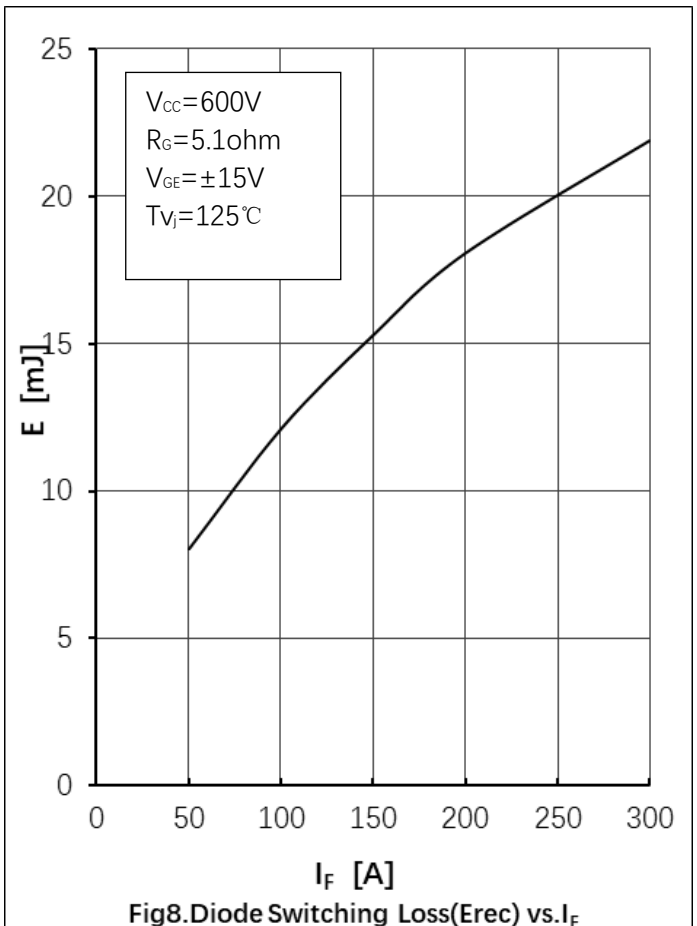
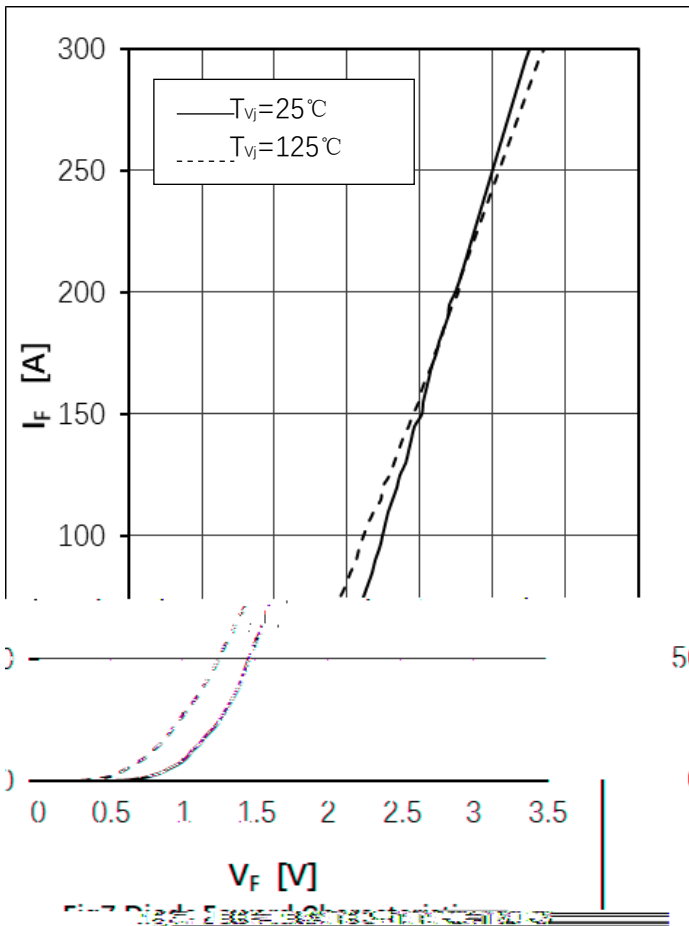
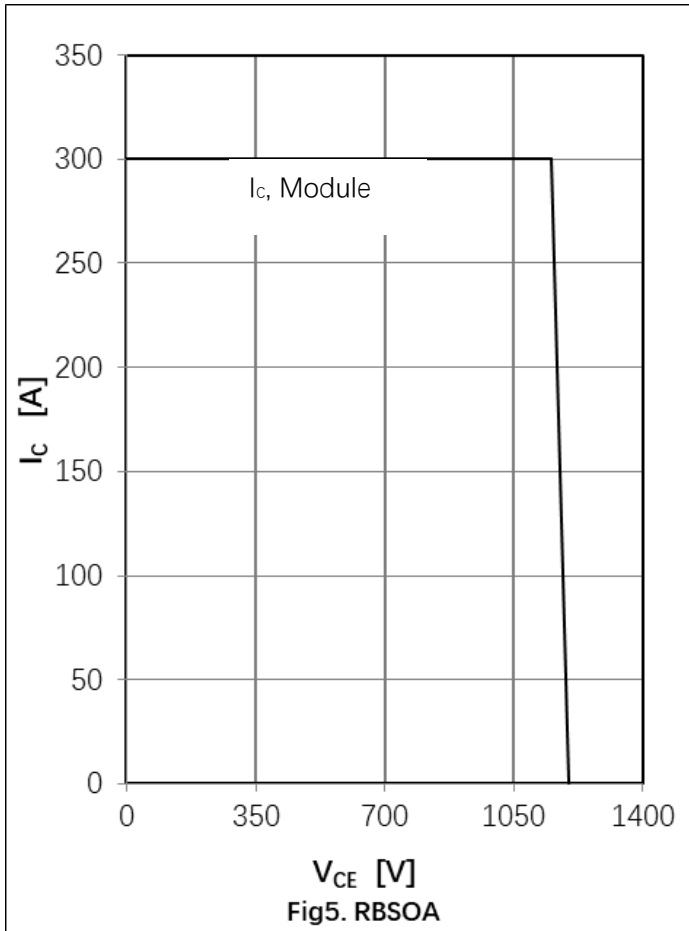


MG150HF12TLC1



V

Characteristics





MG150HF12TLC1

O P
L M

$V_{CC}=600V$

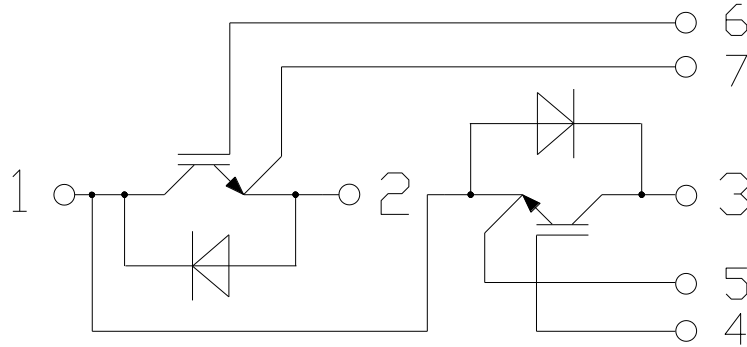
$I_F=150A$

$V_{GE}=\pm 15V$

$T_{Vj}=125^{\circ}C$

τ

● Circuit Diagram



● Package Outline Information

Dimensions in Millimeters

